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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	Coldfire V1
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	CANbus, I ² C, SCI, SPI, USB OTG
Peripherals	LVD, PWM, WDT
Number of I/O	51
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mcf51jm32evlh

1 MCF51JM128 Family Configurations

1.1 Device Comparison

The MCF51JM128 series consists of the devices compared in Table 1.

Table 1. MCF51JM128 Series Device Comparison

Feature	MCF51JM128			MCF51JM64			MCF51JM32		
	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin
Flash memory size (KB)	128			64			32		
RAM size (KB)	16			16			16		
V1 ColdFire core with BDM (background debug module)	Yes								
ACMP (analog comparator)	Yes								
ADC channels (12-bit)	12		8	12		8	12		8
CAN (controller area network)	Yes	Yes	No	Yes	Yes	No	Yes	Yes	No
RNGA + CAU	Yes ¹								
CMT (carrier modulator timer)	Yes								
COP (computer operating properly)	Yes								
IIC1 (inter-integrated circuit)	Yes								
IIC2	Yes	No		Yes	No		Yes	No	
IRQ (interrupt request input)	Yes								
KBI (keyboard interrupts)	8	8	6	8	8	6	8	8	6
LVD (low-voltage detector)	Yes								
MCG (multipurpose clock generator)	Yes								
Port I/O ²	66	51	33	66	51	33	66	51	33
RGPIO (rapid general-purpose I/O)	16	6	0	16	6	0	16	6	0
RTC (real-time counter)	Yes								
SCI1 (serial communications interface)	Yes								
SCI2	Yes								
SPI1 (serial peripheral interface)	Yes								
SPI2	Yes								
TPM1 (timer/pulse-width modulator) channels	6	6	4	6	6	4	6	6	4
TPM2 channels	2								
USBOTG (USB On-The-Go dual-role controller)	Yes								
XOSC (crystal oscillator)	Yes								

¹ Only existed on special part number

² Up to 16 pins on Ports A, H, and J are shared with the ColdFire Rapid GPIO module.

1.2 Block Diagram

Figure 1 shows the connections between the MCF51JM128 series pins and modules.

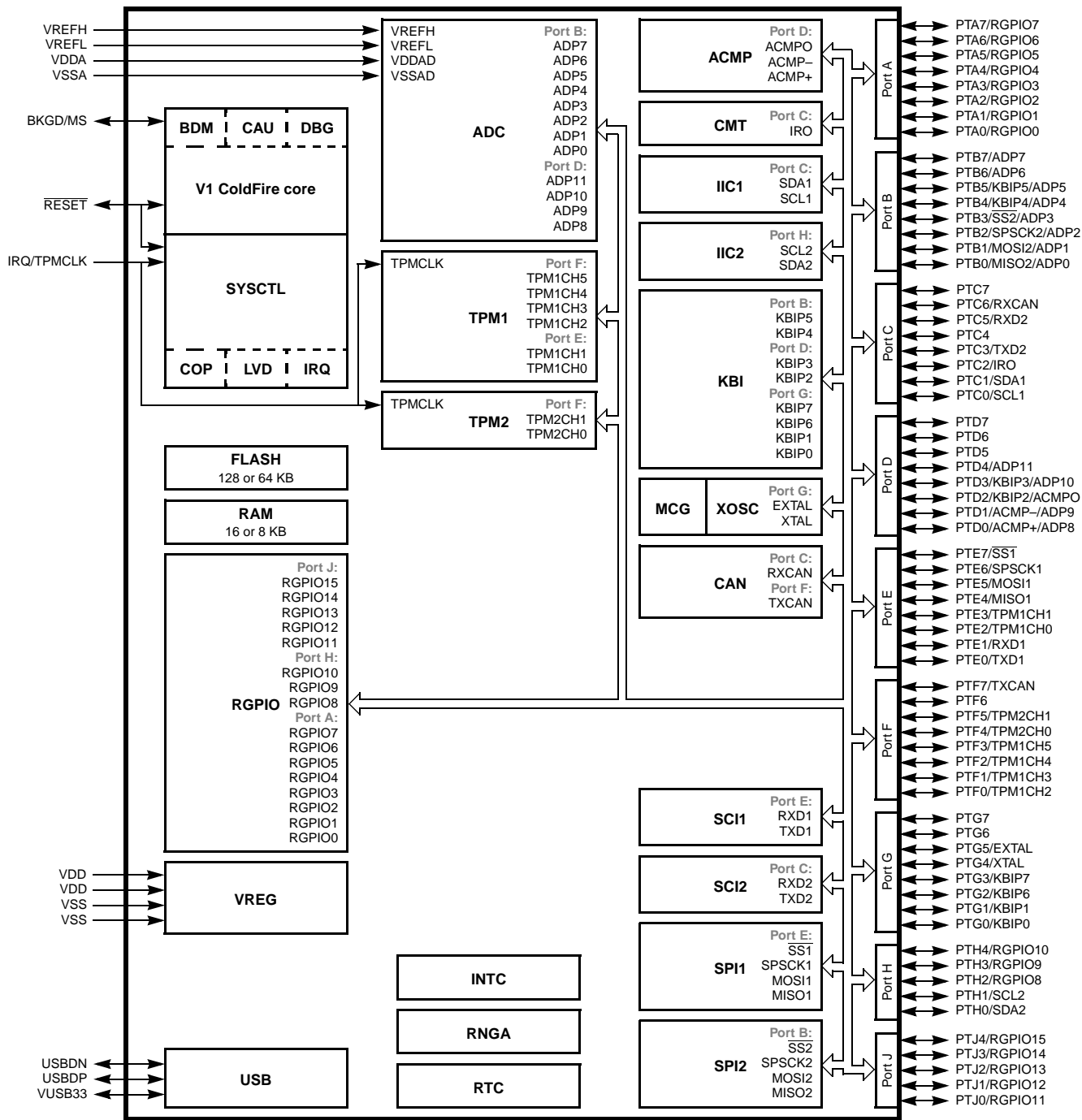


Figure 1. MCF51JM128 Block Diagram

1.3 Features

Table 2 describes the functional units of the MCF51JM128 series.

Table 2. MCF51JM128 Series Functional Units

Unit	Function
CF1CORE (V1 ColdFire core)	Executes programs and interrupt handlers
BDM (background debug module)	Provides a single-pin debugging interface (part of the V1 ColdFire core)
DBG (debug)	Provides debugging and emulation capabilities (part of the V1 ColdFire core)
SYSCCTL (system control)	Provides LVD, COP, external interrupt request, and so on
FLASH (flash memory)	Provides storage for program code and constants
RAM (random-access memory)	Provides storage for program code, constants, and variables
RGPIO (rapid general-purpose input/output)	Allows I/O port access at CPU clock speeds
VREG (voltage regulator)	Controls power management throughout the device
USBOTG (USB On-The-Go)	Supports the USB On-The-Go dual-role controller
ADC (analog-to-digital converter)	Measures analog voltages at up to 12 bits of resolution
TPM1, TPM2 (timer/pulse-width modulators)	Provide a variety of timing-based features
CF1_INTC (interrupt controller)	Controls and prioritizes all device interrupts
CAU (cryptographic acceleration unit)	Co-processor support for DES, 3DES, AES, MD5, and SHA-1
RNGA (random number generator accelerator)	32-bit random number generator that complies with FIPS-140
RTC (real-time counter)	Provides a constant-time base with optional interrupt
ACMP (analog comparator)	Compares two analog inputs
CMT (carrier modulator timer)	Infrared output used for the Remote Controller
IIC1, IIC2 (inter-integrated circuits)	Supports the standard IIC communications protocol
KBI (keyboard interrupt)	Provides pin interrupt capabilities
MCG (multipurpose clock generator)	Provides clocking options for the device, including a phase-locked loop (PLL) and frequency-locked loop (FLL) for multiplying slower reference clock sources
XOSC (crystal oscillator)	Supports low/high range crystals
CAN (controller area network)	Supports standard CAN communications protocol
SCI1, SCI2 (serial communications interfaces)	Serial communications UARTs that can support RS-232 and LIN protocols
SPI1, SPI2 (serial peripheral interfaces)	Provide a 4-pin synchronous serial interface

MCF51JM128 Family Configurations

Figure 4 shows the pinout of the 44-pin LQFP.

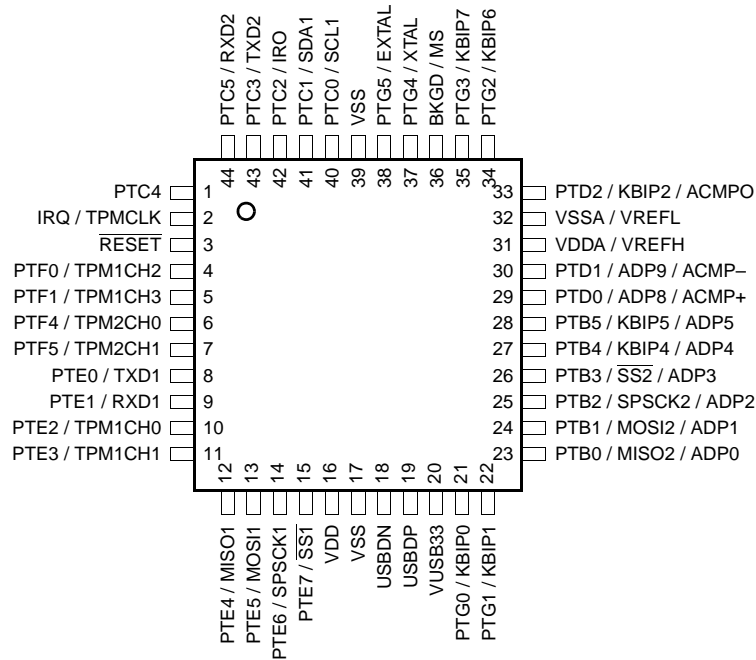


Figure 4. 44-pin LQFP

Table 4 shows the package pin assignments.

Table 4. Pin Assignments by Package and Pin Sharing Priority

Pin Number			<-- Lowest Priority --> Highest		
80	64	44	Port Pin	Alt 1	Alt 2
1	1	1	PTC4		—
2	2	2	—	IRQ	TPMCLK
3	3	3	—	RESET	—
4	4	4	PTF0	TPM1CH2	—
5	5	5	PTF1	TPM1CH3	—
6	6	—	PTF2	TPM1CH4	—
7	7	—	PTF3	TPM1CH5	—
8	8	6	PTF4	TPM2CH0	BUSCLK_OUT
9	9	—	PTC6	RXCAN	—
10	10	—	PTF7	TXCAN	—
11	11	7	PTF5	TPM2CH1	—
12	12	—	PTF6	—	—
13	13	8	PTE0	TXD1	—
14	14	9	PTE1	RXD1	—
15	15	10	PTE2	TPM1CH0	—

Table 4. Pin Assignments by Package and Pin Sharing Priority (continued)

Pin Number			<-- Lowest Priority --> Highest		
80	64	44	Port Pin	Alt 1	Alt 2
49	41	—	PTB7	ADP7	—
50	42	29	PTD0	ADP8	ACMP+
51	43	30	PTD1	ADP9	ACMP-
52	44	31	—	—	VDDA
53	45		—	—	VREFH
54	46	32	—	—	VREFL
55	47		—	—	VSSA
56	48	33	PTD2	KBIP2	ACMPO
57	—	—	PTJ0	RGPIO11	—
58	—	—	PTJ1	RGPIO12	—
59	—	—	PTJ2	RGPIO13	—
60	—	—	PTJ3	RGPIO14	—
61	—	—	PTJ4	RGPIO15	—
62	49	—	PTD3	KBIP3	ADP10
63	50	—	PTD4	ADP11	—
64	51	—	PTD5	—	—
65	52	—	PTD6	—	—
66	53	—	PTD7	—	—
67	54	34	PTG2	KBIP6	—
68	55	35	PTG3	KBIP7	—
69	56	36	—	BKGD	MS
70	57	37	PTG4	XTAL	—
71	58	38	PTG5	EXTAL	—
72	59	39	—	—	VSS
73	—	—	—	—	VDD
74	—	—	PTG6	—	—
75	—	—	PTG7	—	—
76	60	40	PTC0	SCL1	—
77	61	41	PTC1	SDA1	—
78	62	42	PTC2	IRO	—
79	63	43	PTC3	TXD2	—
80	64	44	PTC5	RXD2	—

2 Preliminary Electrical Characteristics

This section contains electrical specification tables and reference timing diagrams for the MCF51JM128 microcontroller, including detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications.

The electrical specifications are preliminary and are from previous designs or design simulations. These specifications may not be fully tested or guaranteed at this early stage of the product life cycle. These specifications will, however, be met for production silicon. Finalized specifications will be published after complete characterization and device qualifications have been completed.

NOTE

The parameters specified in this data sheet supersede any values found in the module specifications.

2.1 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

Table 5. Parameter Classifications

P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

NOTE

The classification is shown in the column labeled C in the parameter tables where appropriate.

2.2 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in Table 6 may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this section.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, V_{SS} or V_{DD}).

- ³ 1s - Single Layer Board, one signal layer
- ⁴ 2s2p - Four Layer Board, 2 signal and 2 power layers

The average chip-junction temperature (T_J) in °C can be obtained from:

$$T_J = T_A + (P_D \times \theta_{JA}) \tag{Eqn. 1}$$

where:

T_A = Ambient temperature, °C
 θ_{JA} = Package thermal resistance, junction-to-ambient, °C/W
 $P_D = P_{int} + P_{I/O}$
 $P_{int} = I_{DD} \times V_{DD}$, Watts — chip internal power
 $P_{I/O}$ = Power dissipation on input and output pins — user determined

For most applications, $P_{I/O} \ll P_{int}$ and can be neglected. An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is:

$$P_D = K \div (T_J + 273^\circ\text{C}) \tag{Eqn. 2}$$

Solving equations 1 and 2 for K gives:

$$K = P_D \times (T_A + 273^\circ\text{C}) + \theta_{JA} \times (P_D)^2 \tag{Eqn. 3}$$

where K is a constant pertaining to the particular part. K can be determined from equation 3 by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and T_J can be obtained by solving equations 1 and 2 iteratively for any value of T_A .

2.4 Electrostatic Discharge (ESD) Protection Characteristics

Although damage from static discharge is much less common on these devices than on early CMOS circuits, normal handling precautions should be used to avoid exposure to static discharge. Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

All ESD testing is in conformity with CDF-AEC-Q00 Stress Test Qualification for Automotive Grade Integrated Circuits. (<http://www.aecouncil.com/>) This device was qualified to AEC-Q100 Rev E.

A device is considered to have failed if, after exposure to ESD pulses, the device no longer meets the device specification requirements. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

Table 8. ESD and Latch-up Test Conditions

Model	Description	Symbol	Value	Unit
Human Body	Series Resistance	R1	1500	Ω
	Storage Capacitance	C	100	pF
	Number of Pulse per pin	–	3	
Latch-up	Minimum input voltage limit		–2.5	V
	Maximum input voltage limit		7.5	V

Table 10. DC Characteristics (continued)

Num	C	Parameter	Symbol	Min	Typ ¹	Max	Unit
7	P	Input low voltage; all digital inputs	V_{IL}	—	—	1.75 1.05	V
		$V_{DD} = 5V$ $V_{DD} = 3V$					
8	P	Input hysteresis; all digital inputs	V_{hys}	$0.06 \times V_{DD}$			mV
9	P	Input leakage current; input only pins ³	$ I_{in} $	—	0.1	1	μA
10	P	High Impedance (off-state) leakage current ³	$ I_{OZ} $	—	0.1	1	μA
11	P	Internal pullup resistors ⁴	R_{PU}	20	45	65	k Ω
12	P	Internal pulldown resistors ⁵	R_{PD}	20	45	65	k Ω
13		Internal pullup resistor to USBDP (to V_{USB33})	R_{PUPD}	900 1425	1300 2400	1575 3090	k Ω
		Idle Transmit					
14	C	Input Capacitance; all non-supply pins	C_{in}	—	—	8	pF
15	D	RAM retention voltage ⁶	V_{RAM}	—	0.6	1.0	V
16	P	POR rearm voltage	V_{POR}	0.9	1.4	2.0	V
17	D	POR rearm time	t_{POR}	10	—	—	μs
18	P	Low-voltage detection threshold — high range	V_{LVD1}	3.9 4.0	4.0 4.1	4.1 4.2	V
		V_{DD} falling V_{DD} rising					
19	P	Low-voltage detection threshold — low range	V_{LVD0}	2.48 2.54	2.56 2.62	2.64 2.70	V
		V_{DD} falling V_{DD} rising					
20	C	Low-voltage warning threshold — high range 1	V_{LVW3}	4.5 4.6	4.6 4.7	4.7 4.8	V
		V_{DD} falling V_{DD} rising					
21	P	Low-voltage warning threshold — high range 0	V_{LVW2}	4.2 4.3	4.3 4.4	4.4 4.5	V
		V_{DD} falling V_{DD} rising					
22	P	Low-voltage warning threshold low range 1	V_{LVW1}	2.84 2.90	2.92 2.98	3.00 3.06	V
		V_{DD} falling V_{DD} rising					
23	C	Low-voltage warning threshold — low range 0	V_{LVW0}	2.66 2.72	2.74 2.80	2.82 2.88	V
		V_{DD} falling V_{DD} rising					
24	T	Low-voltage inhibit reset/recover hysteresis	V_{hys}	— —	100 60	— —	mV
		5 V 3 V					

2.7 Analog Comparator (ACMP) Electricals

Table 12. Analog Comparator Electrical Specifications

Num	C	Rating	Symbol	Min	Typical	Max	Unit
1		Supply voltage	V_{DD}	2.7	—	5.5	V
2		Supply current (active)	I_{DDAC}	—	20	35	μA
3		Analog input voltage	V_{AIN}	$V_{SS} - 0.3$	—	V_{DD}	V
4		Analog input offset voltage	V_{AIO}		20	40	mV
5		Analog Comparator hysteresis	V_H	3.0	6.0	20.0	mV
6		Analog input leakage current	I_{ALKG}	--	--	1.0	μA
7		Analog Comparator initialization delay	t_{AINIT}	—	—	1.0	μs
8		Bandgap Voltage Reference Factory trimmed at $V_{DD} = 3.0\text{ V}$, Temp = 25°C	V_{BG}	1.19	1.20	1.21	V

2.8 ADC Characteristics

Table 13. 5 Volt 12-bit ADC Operating Conditions

Characteristic	Conditions	Symb	Min	Typ ¹	Max	Unit	Comment
Supply voltage	Absolute	V_{DDA}	2.7	—	5.5	V	
	Delta to V_{DD} ($V_{DD} - V_{DDA}$) ²	ΔV_{DDA}	-100	0	+100	mV	
Ground voltage	Delta to V_{SS} ($V_{SS} - V_{SSA}$) ²	ΔV_{SSA}	-100	0	+100	mV	
Ref Voltage High		V_{REFH}	2.7	V_{DDA}	V_{DDA}	V	
Ref Voltage Low		V_{REFL}	V_{SSA}	V_{SSA}	V_{SSA}	V	
Input Voltage		V_{ADIN}	V_{REFL}	—	V_{REFH}	V	
Input Capacitance		C_{ADIN}	—	4.5	5.5	pF	
Input Resistance		R_{ADIN}	—	3	5	k Ω	
Analog Source Resistance	12 bit mode $f_{ADCK} > 4\text{MHz}$ $f_{ADCK} < 4\text{MHz}$	R_{AS}	—	—	2	k Ω	External to MCU
	10 bit mode $f_{ADCK} > 4\text{MHz}$ $f_{ADCK} < 4\text{MHz}$		—	—	5		
	8 bit mode (all valid f_{ADCK})		—	—	10		
ADC Conversion Clock Freq.	High Speed (ADLPC=0)	f_{ADCK}	0.4	—	8.0	MHz	
	Low Power (ADLPC=1)		0.4	—	4.0		

¹ Typical values assume $V_{DDA} = 5.0\text{V}$, Temp = 25°C, $f_{ADCK} = 1.0\text{MHz}$ unless otherwise stated. Typical values are for reference only and are not tested in production.

² DC potential difference.

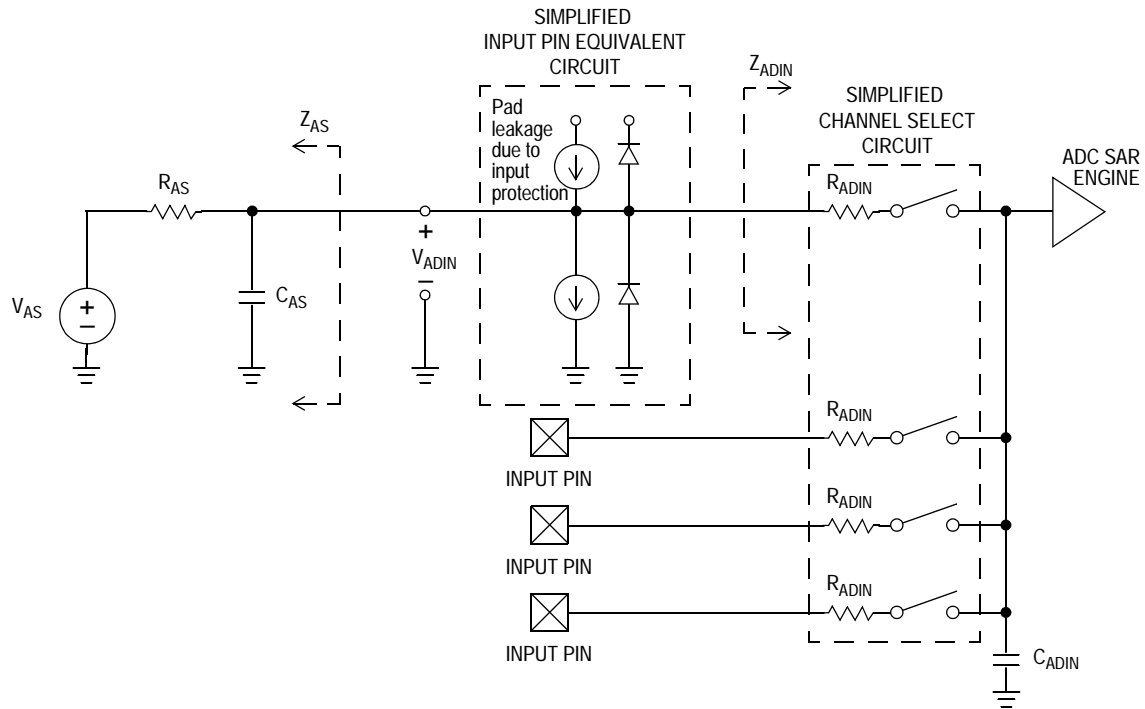


Figure 9. ADC Input Impedance Equivalency Diagram

Table 14. 5 Volt 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

Characteristic	Conditions	C	Symb	Min	Typ ¹	Max	Unit	Comment
Supply Current ADLPC=1 ADLSMP=1 ADCO=1		T	I_{DDAD}	—	133	—	μA	
Supply Current ADLPC=1 ADLSMP=0 ADCO=1		T	I_{DDAD}	—	218	—	μA	
Supply Current ADLPC=0 ADLSMP=1 ADCO=1		T	I_{DDAD}	—	327	—	μA	
Supply Current ADLPC=0 ADLSMP=0 ADCO=1		P	I_{DDAD}	—	0.582	1	mA	
Supply Current	Stop, Reset, Module Off		I_{DDAD}	—	0.011	1	μA	
ADC Asynchronous Clock Source	High Speed (ADLPC=0)	T	f_{ADACK}	2	3.3	5	MHz	$t_{ADACK} = 1/f_{ADACK}$
	Low Power (ADLPC=1)			1.25	2	3.3		

Table 14. 5 Volt 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Characteristic	Conditions	C	Symb	Min	Typ ¹	Max	Unit	Comment
Conversion Time (Including sample time)	Short Sample (ADLSMP=0)	T	t_{ADC}	—	20	—	ADCK cycles	See Table 9 for conversion time variances
	Long Sample (ADLSMP=1)			—	40	—		
Sample Time	Short Sample (ADLSMP=0)	T	t_{ADS}	—	3.5	—	ADCK cycles	
	Long Sample (ADLSMP=1)			—	23.5	—		
Total Unadjusted Error	12 bit mode	T	E_{TUE}	—	± 3.0	—	LSB ²	Includes quantization
	10 bit mode	P		—	± 1	± 2.5		
	8 bit mode	T		—	± 0.5	± 1.0		
Differential Non-Linearity	12 bit mode	T	DNL	—	± 1.75	—	LSB ²	
	10 bit mode ³	P		—	± 0.5	± 1.0		
	8 bit mode ³	T		—	± 0.3	± 0.5		
Integral Non-Linearity	12 bit mode	T	INL	—	± 1.5	—	LSB ²	
	10 bit mode	T		—	± 0.5	± 1.0		
	8 bit mode	T		—	± 0.3	± 0.5		
Zero-Scale Error	12 bit mode	T	E_{ZS}	—	± 1.5	—	LSB ²	$V_{ADIN} = V_{SSAD}$
	10 bit mode	P		—	± 0.5	± 1.5		
	8 bit mode	T		—	± 0.5	± 0.5		
Full-Scale Error	12 bit mode	T	E_{FS}	—	± 1	—	LSB ²	$V_{ADIN} = V_{DDAD}$
	10 bit mode	T		—	± 0.5	± 1		
	8 bit mode	T		—	± 0.5	± 0.5		
Quantization Error	12 bit mode	D	E_Q	—	-1 to 0	—	LSB ²	
	10 bit mode			—	—	± 0.5		
	8 bit mode			—	—	± 0.5		
Input Leakage Error	12 bit mode	D	E_{IL}	—	± 1	—	LSB ²	Pad leakage ⁴ * R_{AS}
	10 bit mode			—	± 0.2	± 2.5		
	8 bit mode			—	± 0.1	± 1		
Temp Sensor Voltage	25°C	D	V_{TEMP25}	—	1.396	—	V	
Temp Sensor Slope	-40°C - 25°C	D	m	—	3.266	—	mV/°C	
	25°C - 125°C			—	3.638	—		

¹ Typical values assume $V_{DDA} = 5.0V$, Temp = 25°C, $f_{ADCK} = 1.0MHz$ unless otherwise stated. Typical values are for reference only and are not tested in production.

² $1 \text{ LSB} = (V_{REFH} - V_{REFL})/2^N$

³ Monotonicity and No-Missing-Codes guaranteed in 10 bit and 8 bit modes

⁴ Based on input pad leakage current. Refer to pad electricals.

2.9 External Oscillator (XOSC) Characteristics

Table 15. Oscillator Electrical Specifications (Temperature Range = -40 to 105°C Ambient)

Num	C	Rating	Symbol	Min	Typ ¹	Max	Unit	
1		Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1) • Low range (RANGE = 0) • High range (RANGE = 1) FEE or FBE mode ² • High range (RANGE = 1) PEE or PBE mode ³ • High range (RANGE = 1, HGO = 1) BLPE mode • High range (RANGE = 1, HGO = 0) BLPE mode	f_{lo}	32	—	38.4	kHz	
			f_{hi-ll}	1	—	5	MHz	
			f_{hi-pll}	1	—	16	MHz	
			f_{hi-hgo}	1	—	16	MHz	
			f_{hi-lp}	1	—	8	MHz	
2		Load capacitors	C_1 C_2	See crystal or resonator manufacturer's recommendation.				
3		Feedback resistor • Low range (32 kHz to 38.4 kHz) • High range (1 MHz to 16 MHz)	R_F		10 1		MΩ MΩ	
4	—	Series resistor • Low range, low gain (RANGE = 0, HGO = 0) • Low range, high gain (RANGE = 0, HGO = 1) • High range, low gain (RANGE = 1, HGO = 0) • High range, high gain (RANGE = 1, HGO = 1)	R_S	≥ 8 MHz	—	0	—	kΩ
				4 MHz	—	100	—	
				1 MHz	—	0	—	
				≥ 8 MHz	—	0	0	
				4 MHz	—	0	10	
				1 MHz	—	0	20	
5	T	Crystal start-up time ⁴ • Low range, low gain (RANGE = 0, HGO = 0) • Low range, high gain (RANGE = 0, HGO = 1) • High range, low gain (RANGE = 1, HGO = 0) ⁵ • High range, high gain (RANGE = 1, HGO = 1) ⁵	$t_{CSTL-LP}$	—	200	—	ms	
			$t_{CSTL-HGO}$	—	400	—		
			$t_{CSTH-LP}$	—	5	—		
			$t_{CSTH-HGO}$	—	15	—		
6	T	Square wave input clock frequency (EREFS = 0, ERCLKEN = 1) • FEE or FBE mode ² • PEE or PBE mode ³ • BLPE mode	f_{extal}	0.03125	—	5	MHz	
				1	—	16	MHz	
				0	—	40	MHz	

¹ Data in Typical column was characterized at 5.0 V, 25°C or is typical recommended value.

² When MCG is configured for FEE or FBE mode, input clock source must be divisible using RDIV to within the range of 31.25 kHz to 39.0625 kHz.

³ When MCG is configured for PEE or PBE mode, input clock source must be divisible using RDIV to within the range of 1 MHz to 2 MHz.

⁴ This parameter is characterized and not tested on each device. Proper PC board-layout procedures must be followed to achieve specifications.

⁵ 4 MHz crystal

2.10 MCG Specifications

Table 16. MCG Frequency Specifications (Temperature Range = -40 to 125°C Ambient)

Num	C	Rating	Symbol	Min	Typical ¹	Max	Unit	
1	P	Internal reference frequency - factory trimmed at $V_{DD} = 5\text{ V}$ and temperature = 25 °C	f_{int_ft}	—	32.768	—	kHz	
2	P	Average internal reference frequency – untrimmed	f_{int_ut}	31.25	—	39.0625	kHz	
3	T	Internal reference startup time	t_{irefst}	—	60	100	μs	
4	P	DCO output frequency range - untrimmed ²	f_{dco_ut}	Low range (DRS=00)	16	—	20	MHz
	Mid range (DRS=01)			32	—	40		
	High range (DRS=10)			48	—	60		
5	P	DCO output frequency ² Reference = 32768Hz and DMX32 = 1	f_{dco_DMX32}	Low range (DRS=00)	—	19.92	—	MHz
	P			Mid range (DRS=01)	—	39.85	—	
	P			High range (DRS=10)	—	59.77	—	
6	D	Resolution of trimmed DCO output frequency at fixed voltage and temperature (using FTRIM)	$\Delta f_{dco_res_t}$	—	±0.1	±0.2	% f_{dco}	
7	D	Resolution of trimmed DCO output frequency at fixed voltage and temperature (not using FTRIM)	$\Delta f_{dco_res_t}$	—	±0.2	±0.4	% f_{dco}	
8	D	Total deviation of trimmed DCO output frequency over voltage and temperature	Δf_{dco_t}	—	0.5 -1.0	±2	% f_{dco}	
9	D	Total deviation of trimmed DCO output frequency over fixed voltage and temperature range of 0 – 70 °C	Δf_{dco_t}	—	±0.5	±1	% f_{dco}	
10	D	FLL acquisition time ³	$t_{fill_acquire}$	—	—	1	ms	
11	D	PLL acquisition time ⁴	$t_{pll_acquire}$	—	—	1	ms	
12	D	Long term Jitter of DCO output clock (averaged over 2ms interval) ⁵	C_{jitter}	—	0.02	0.2	% f_{dco}	
13	D	VCO operating frequency	f_{vco}	7.0	—	55.0	MHz	
14	D	Jitter of PLL output clock measured over 625 ns ⁶	$f_{pll_jitter_625ns}$	—	0.566 ⁵	—	% f_{pll}	
15	D	Lock entry frequency tolerance ⁷	D_{lock}	±1.49	—	±2.98	%	
16	D	Lock exit frequency tolerance ⁸	D_{unl}	±4.47	—	±5.97	%	
17	D	Lock time — FLL	t_{fill_lock}	—	—	$t_{fill_acquire} + 1075(1/f_{int_t})$	s	
18	D	Lock time — PLL	t_{pll_lock}	—	—	$t_{pll_acquire} + 1075(1/f_{pll_ref})$	s	
19	D	Loss of external clock minimum frequency – RANGE = 0	f_{loc_low}	$(3/5) \times f_{int}$	—	—	kHz	

¹ Data in Typical column was characterized at 5.0 V, 25C or is typical recommended value

² The resulting bus clock frequency should not exceed the maximum specified bus clock frequency of the device.

³ This specification applies to any time the FLL reference source or reference divider is changed, trim value changed or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

⁴ This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

2.12 SPI Characteristics

Table 20 and Figure 14 through Figure 17 describe the timing requirements for the SPI system.

Table 20. SPI Timing

No.	C	Function	Symbol	Min	Max	Unit
—	D	Operating frequency Master Slave	f_{op}	$f_{Bus}/2048$ 0	$f_{Bus}/2$ $f_{Bus}/4$	Hz
1	D	SPSCK period Master Slave	t_{SPSCK}	2 4	2048 —	t_{cyc} t_{cyc}
2	D	Enable lead time Master Slave	t_{Lead}	1/2 1	— —	t_{SPSCK} t_{cyc}
3	D	Enable lag time Master Slave	t_{Lag}	1/2 1	— —	t_{SPSCK} t_{cyc}
4	D	Clock (SPSCK) high or low time Master Slave	t_{WSPSCK}	$t_{cyc} - 30$ $t_{cyc} - 30$	$1024 t_{cyc}$ —	ns ns
5	D	Data setup time (inputs) Master Slave	t_{SU}	15 15	— —	ns ns
6	D	Data hold time (inputs) Master Slave	t_{HI}	0 25	— —	ns ns
7	D	Slave access time	t_a	—	1	t_{cyc}
8	D	Slave MISO disable time	t_{dis}	—	1	t_{cyc}
9	D	Data valid (after SPSCK edge) Master Slave	t_v	— —	25 25	ns ns
10	D	Data hold time (outputs) Master Slave	t_{HO}	0 0	— —	ns ns
11	D	Rise time Input Output	t_{RI} t_{RO}	— —	$t_{cyc} - 25$ 25	ns ns
12	D	Fall time Input Output	t_{FI} t_{FO}	— —	$t_{cyc} - 25$ 25	ns ns

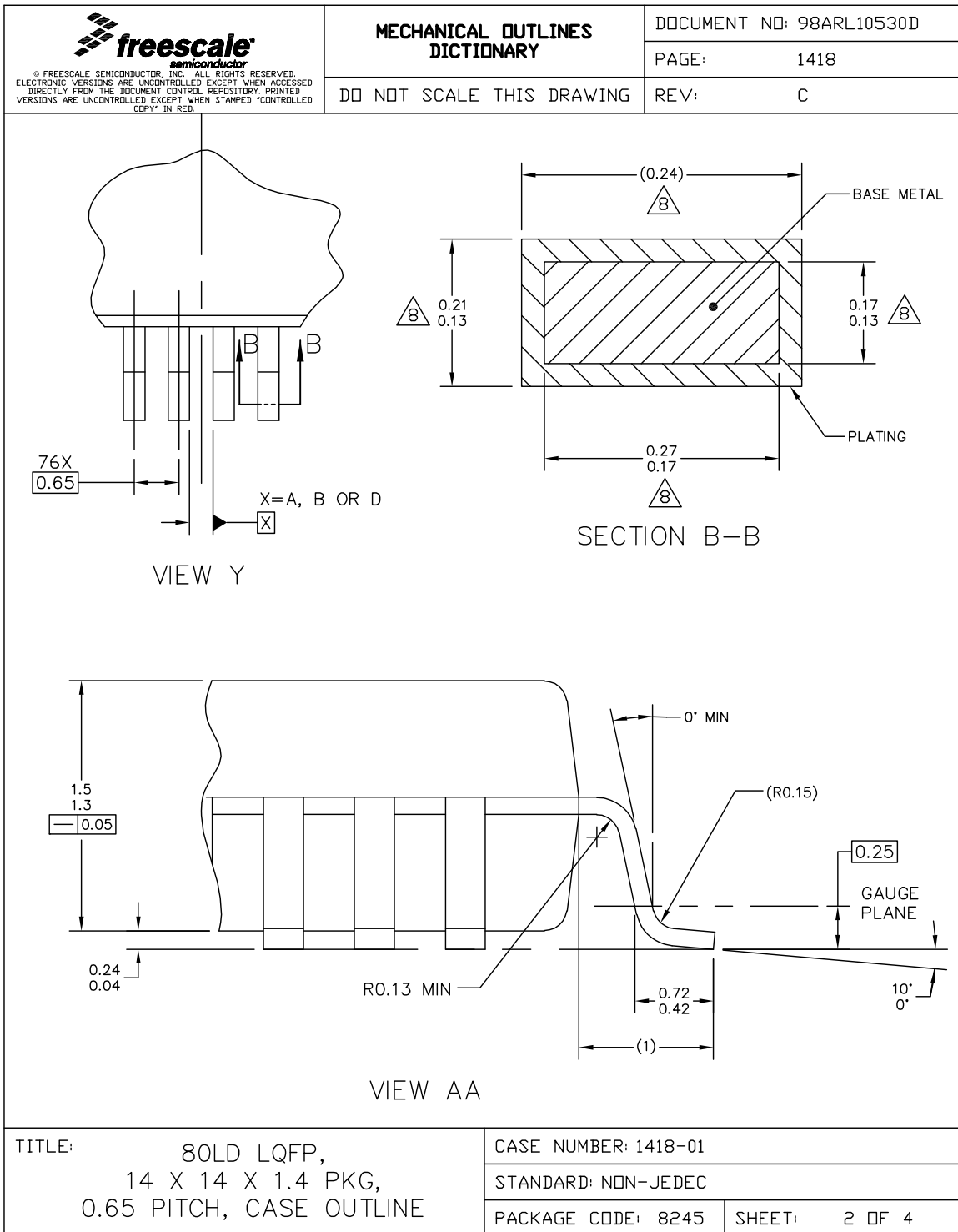


Figure 19. 80-pin LQFP Diagram - II

3.2 64-pin LQFP

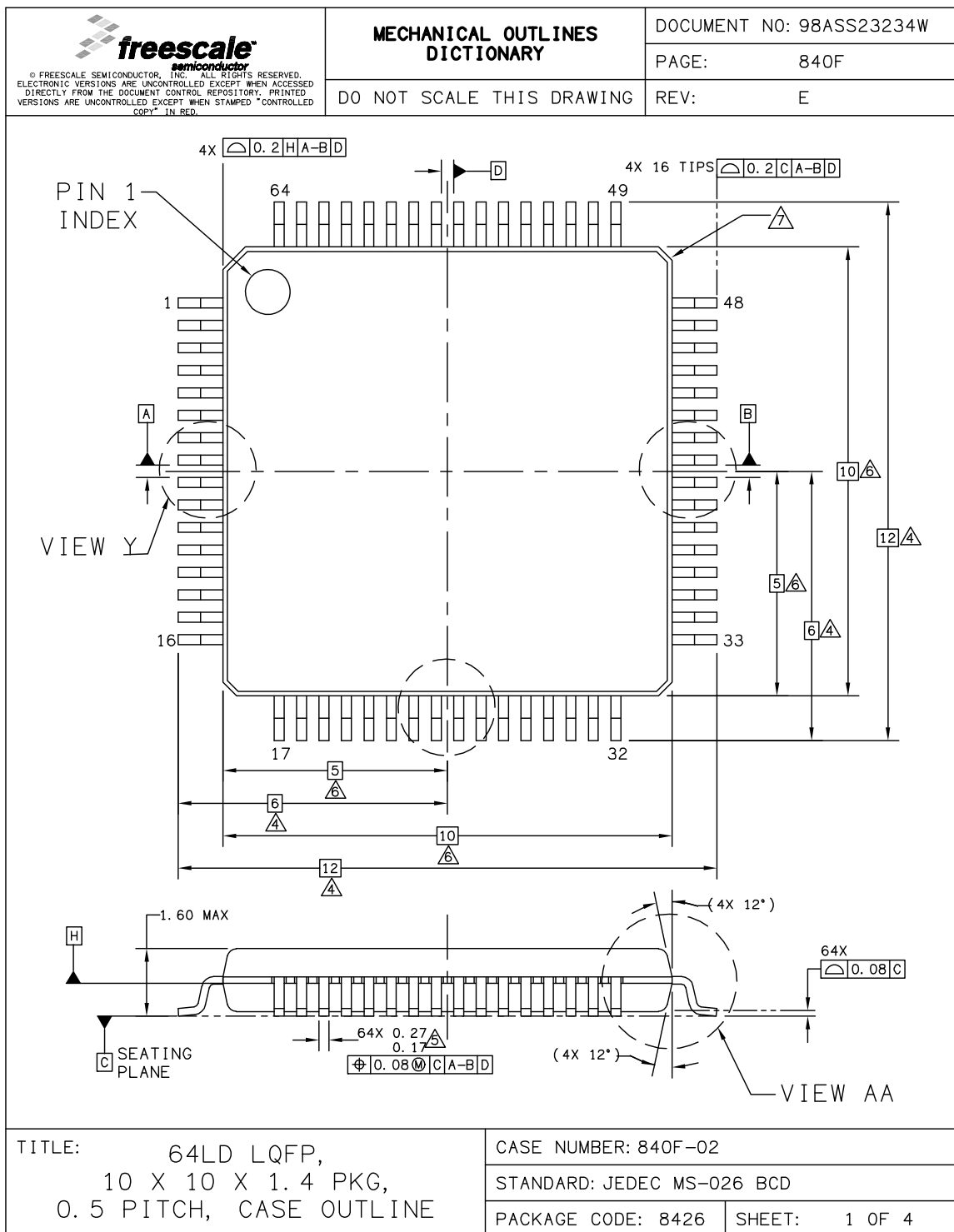


Figure 21. 64-pin LQFP Diagram - I

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	DO NOT SCALE THIS DRAWING	PAGE: 840B REV: B
<p>NOTES:</p> <ol style="list-style-type: none"> DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETER. DATUM PLANE -H- IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE. DATUMS A-B AND -D- TO BE DETERMINED AT DATUM PLANE -H-. <p>⑤ DIMENSIONS TO BE DETERMINED AT SEATING PLANE -C-.</p> <p>⑥ DIMENSIONS DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PER SIDE. DIMENSIONS DO INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-.</p> <p>⑦ DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT.</p>		
TITLE: 64LD QFP (14 X 14)	CASE NUMBER: 840B-01	
	STANDARD: NON-JEDEC	
	PACKAGE CODE: 6057	SHEET: 3 OF 4

Figure 26. 64-pin QFP Diagram - III

3.4 44-pin LQFP

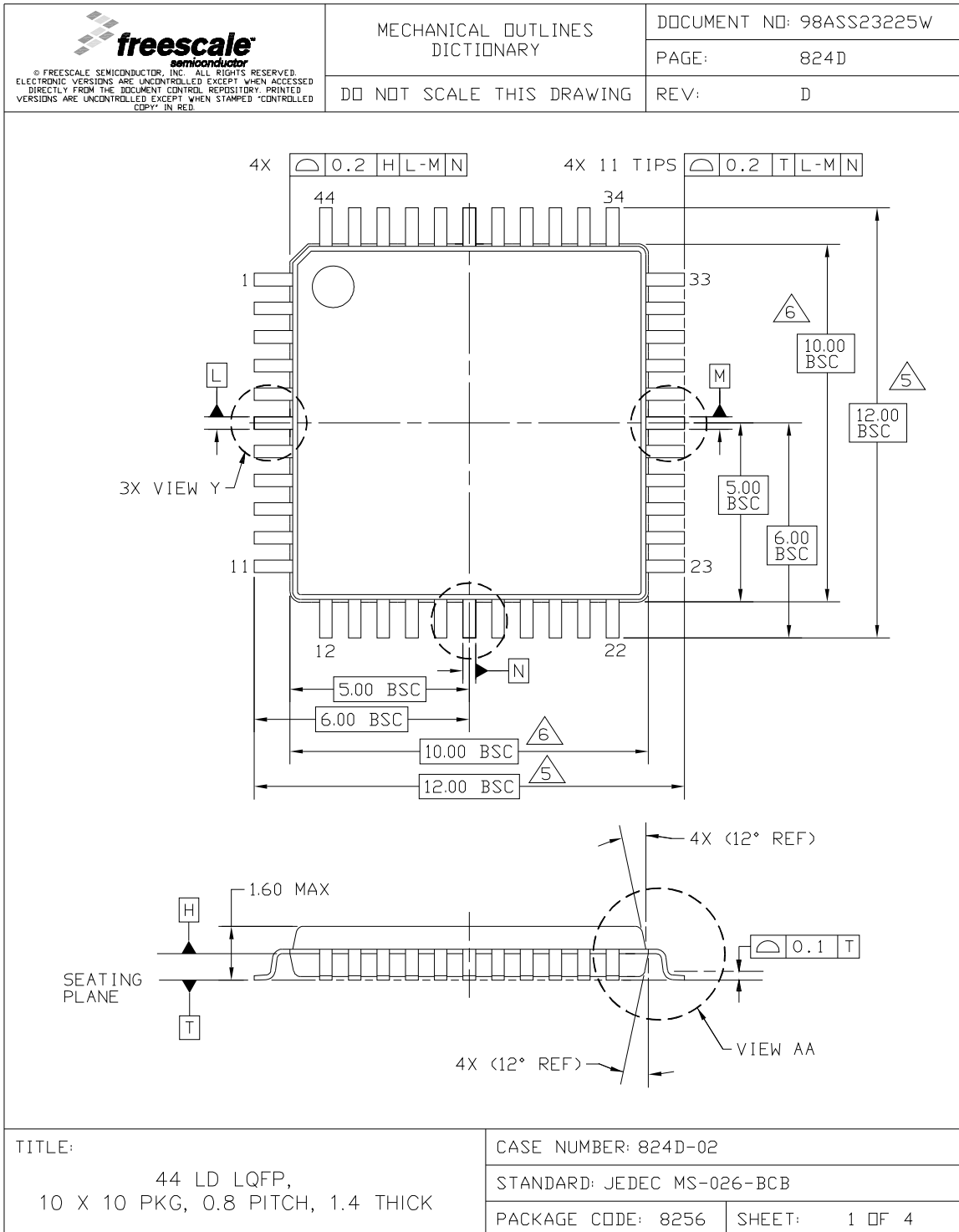


Figure 27. 44-pin LQFP Diagram - I

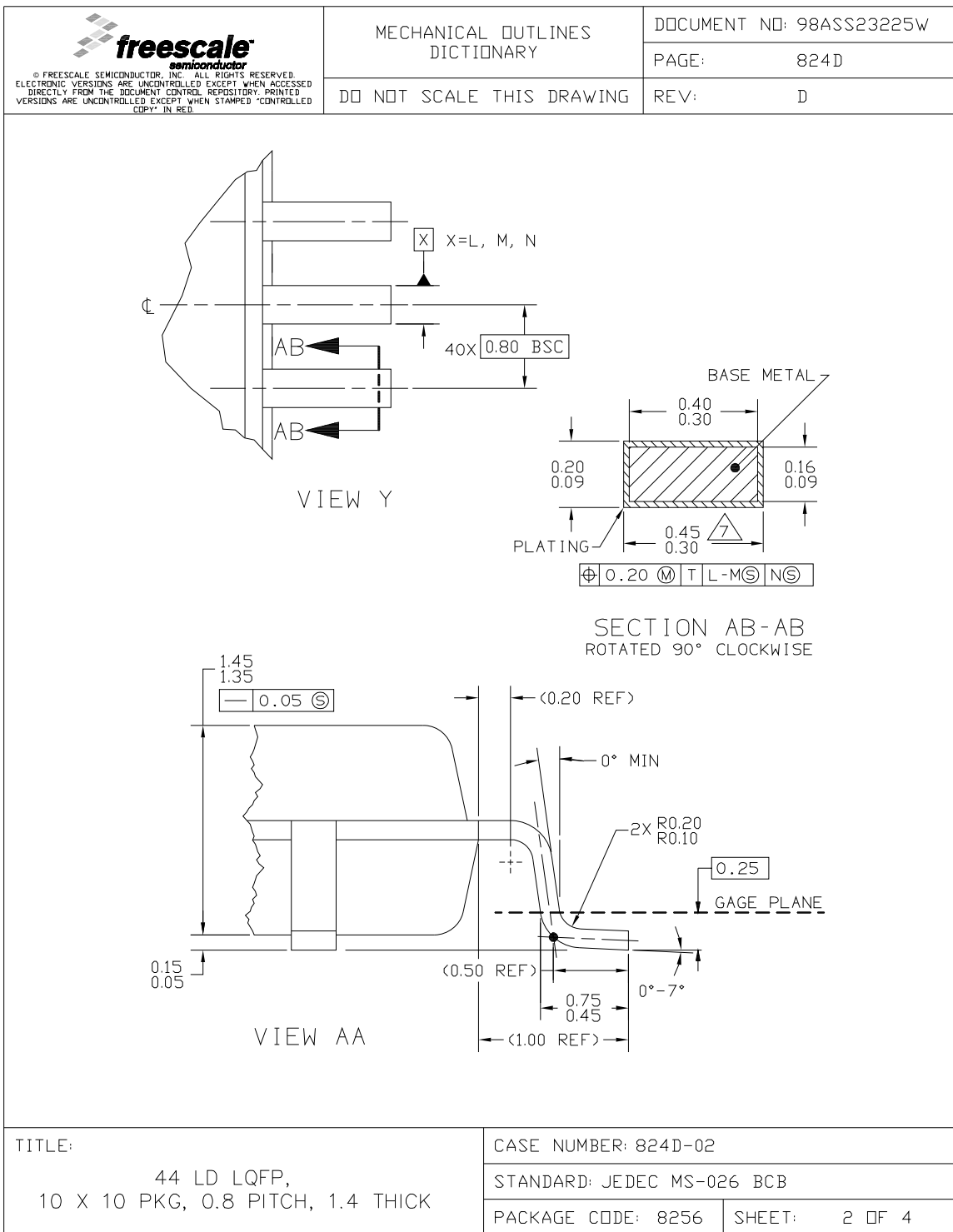


Figure 28. 44-pin LQFP Diagram - II

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